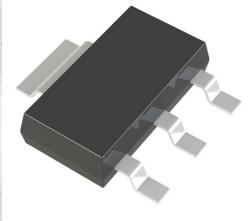


ZVN0545GTA Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	ZVN0545GTA-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	ZVN0545GTA
Description	MOSFET N-CH 450V 140MA SOT223
Detailed Description	N-Channel 450 V 140mA (Ta) 2W (Ta) Surface Moun t SOT-223-3

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
ZVN0545GTA	Diodes Incorporated
Series:	Product Status:
-	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
450 V	140mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	500hm @ 100mA, 10V
Vgs(th) (Max) @ ld:	Vgs (Max):
3V @ 1mA	±20V
Input Capacitance (Ciss) (Max) @ Vds:	FET Feature:
70 pF @ 25 V	
Power Dissipation (Max):	Operating Temperature:
2W (Ta)	-55°C ~ 150°C (TJ)
Mounting Type:	Supplier Device Package:
Surface Mount	SOT-223-3
Package / Case:	Base Product Number:
TO-261-4, TO-261AA	ZVN0545

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0095	





ZVN0545G

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Product Summary

BV _{DSS}	Rds(on)	ID TA = +25°C	
450V	50Ω @ V _{GS} = 10V	140mA	

Description and Applications

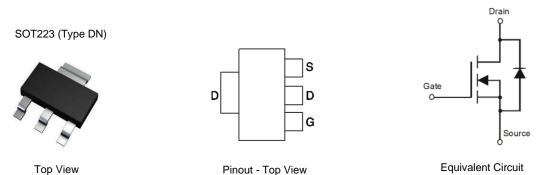
This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for highefficiency power-management applications.

Features and Benefits

- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.112 grams (Approximate)



Top View

Ordering Information (Note 4)

Orderable Part Number	Packago	Pa	Packing		
	Package	Qty.	Carrier		
ZVN0545GTA	SOT223 (Type DN)	1,000	Tape & Reel		

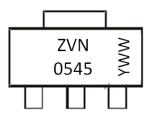
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



ZVN0545 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 4 = 2024) WW or $\overline{W}W = Week Code$ (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		Vdss	450	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current V _{GS} = 10V	T _A = +25°C	lo	140	mA
Pulsed Drain Current		ldм	600	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation	T _A = +25°C	PD	2	W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BVDSS	450	—	_	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS		_	10 400	μA μA	V _{DS} = 450V, V _{GS} = 0V V _{DS} =405V, V _{GS} =0V, T=+125°C (Note 6)
Gate-Source Leakage	I _{GSS}	_	_	±20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS	•					
Gate Threshold Voltage	Vgs(th)	1	—	3	V	V _{DS} = V _{GS} , I _D = 1mA
Static Drain-Source On-State Resistance (Note 5)	RDS(ON)	_	_	50	Ω	V _{GS} = 10V, I _D = 100mA
On-State Drain Current (Note 5)	ID(ON)	150	—	_	mA	V _{DS} =25V, V _{GS} =10V
Forward Transconductance (Notes 5 and 6)	g fs	100	_	—	mS	V _{DS} =25V,I _D =100mA
DYNAMIC CHARACTERISTICS (Note 6)						
Input Capacitance	Ciss		—	70	pF	
Output Capacitance	Coss		—	10	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$
Reverse Transfer Capacitance	Crss	-	_	4	pF	
Turn-On Delay Time (Note 7)	t _{D(ON)}	—	_	7	ns	
Turn-On Rise Time (Note 7)	tR	_	_	7	ns	
Turn-Off Delay Time (Note 7)	tD(OFF)	_	—	16	ns	V _{DD} = 25V, I _D =100mA
Turn-Off Fall Time (Note 7)	tF	_	_	10	ns	

Notes: 5. Measured under pulsed conditions. Width=300 μ s. Duty cycle ≤ 2%.

6. Sample test. 7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.

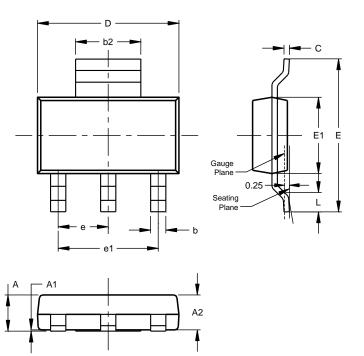
SOT223 (Type DN)



ZVN0545G

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

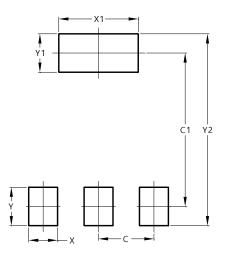


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All [All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



IMPORTANT NOTICE

1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5 products provided Diodes' Standard Terms and Conditions of Sale Diodes' are subiect to (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

9. This Notice may be periodically updated with the most recent version available at https://www.diodes.com/about/company/terms-and-conditions/important-notice

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners. © 2024 Diodes Incorporated. All Rights Reserved.

www.diodes.com



OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

	<section-header></section-header>		
Marginary Marginary Marginary	Market	Marchine Marchine Image: Control of the sector of the sec	





Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.